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1 Electrical ratings

Table 2: Absolute maximum ratings

Cumbal	Devementer	Value	I Imit	
Symbol	Parameter	D²PAK, TO-220	TO-220FP	Unit
Vces	Collector-emitter voltage (V _{GE} = 0 V)	600		V
Ic ⁽¹⁾	Continuous collector current at T _C = 25 °C	35	16	Α
IC. A	Continuous collector current at T _C = 100 °C	20	10	Α
IcL ⁽²⁾	Turn-off latching current	75		Α
ICP ⁽³⁾	Pulsed collector current	75		Α
V _{GE}	Gate-emitter voltage	±20		V
lF	Diode RMS forward current at T _C = 25 °C	20		Α
I _{FSM}	Surge non repetitive forward current t _p = 10 ms sinusoidal	50		Α
Ртот	Total dissipation at T _C = 25 °C	125	32	W
Viso	Insulation withstand voltage (RMS) from all three leads to external heat-sink (t=1 s; Tc= 25 °C)	2500		V
t _{scw}	Short-circuit withstand time V_{CE} = 300 V, T_j = 125 °C, R_G = 10 Ω , V_{GE} = 12 V	10		μs
T _{stg}	Storage temperature range	- 55 to 150		°C
TJ	Operating junction temperature range			

Notes:

⁽¹⁾Calculated according to the iterative formula:

$$I_{C}(T_{C}) = \frac{T_{j(max)} - T_{C}}{R_{thj-c} \times V_{CE(sat)(max)}(T_{j(max)}, I_{C}(T_{C}))}$$

Table 3: Thermal data

Cumbal	Parameter	Value	Unit	
Symbol	Parameter	D²PAK, TO-220	TO-220FP	Unit
R _{thj-case}	Thermal resistance junction-case IGBT	1	3.9	
R _{thj-case}	Thermal resistance junction-case diode	3	5.6	°C/W
R _{thj-amb}	Thermal resistance junction-ambient	62.5		

 $^{^{(2)}}V_{clamp}$ = 80 % VCES, VGE = 15 V, RG = 10 $\Omega,$ TJ = 150 °C.

⁽³⁾Pulse width limited by maximum junction temperature.

2 Electrical characteristics

T_C = 25 °C unless otherwise specified

Table 4: Static characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _(BR) CES	Collector-emitter breakdown voltage	Ic = 1 mA, V _{GE} = 0 V	600			٧
	Callagtar amittar acturation	V _{GE} =15 V, I _C = 12 A		2.0	2.75	
V _{CE(sat)}	Collector-emitter saturation voltage	V _{GE} = 15 V, I _C = 12 A, T _C = 125 °C		1.65		V
V _{GE(th)}	Gate threshold voltage	V _{CE} = V _{GE} , I _C = 250 μA	4.5		6.5	V
		V _{CE} = 600 V, V _{GE} = 0 V			150	μΑ
ICES	Collector cut-off current	V _{CE} =600 V, V _{GE} = 0 V, T _C = 125 °C ⁽¹⁾			1	mA
I _{GES}	Gate-emitter leakage current	$V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$			±100	nA

Notes:

Table 5: Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Cies	Input capacitance		-	1170	ı	
Coes	Output capacitance	V _{CE} = 25 V, f = 1 MHz,	-	127	-	pF
C _{res}	Reverse transfer capacitance	V _{GE} = 0 V	-	28	-	Pi
Q_g	Total gate charge	$V_{CE} = 480 \text{ V}, I_{C} = 12 \text{ A},$	-	55	-	
Qge	Gate-emitter charge	V _{GE} = 0 to 15 V (see <i>Figure 20: " Gate</i>	-	11	ı	nC
Qgc	Gate-collector charge	charge test circuit")	-	26	-	

 $[\]ensuremath{^{(1)}}\mbox{Defined}$ by design, not subject to production test.

Table 6: Switching on/off (inductive load)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{d(on)}	Turn-on delay time	Vcc = 480 V, Ic = 12 A,	-	30	-	ns
tr	Current rise time	$R_G = 10 \Omega$, $V_{GE} = 15 V$	-	8	-	ns
(di/dt) _{on}	Turn-on current slope	(see Figure 19: " Test circuit for inductive load switching" and Figure 21: " Switching waveform")		1450	ı	A/μs
t _{d(on)}	Turn-on delay time	Vcc = 480 V, Ic = 12 A,	-	30	-	ns
t _r	Current rise time	R_G = 10 Ω, V_{GE} = 15 V, T_{C} =125 °C		8	-	ns
(di/dt) _{on}	Turn-on current slope	(see Figure 19: " Test circuit for inductive load switching" and Figure 21: " Switching waveform")	-	1380	ı	A/μs
$t_{r(\text{Voff})}$	Off voltage rise time	$V_{CC} = 480 \text{ V}, I_C = 12 \text{ A},$	-	35	-	ns
t _{d(off)}	Turn-off delay time	$R_G = 10 \Omega$, $V_{GE} = 15 V$	-	105	-	ns
t _f	Current fall time	(see Figure 19: " Test circuit for inductive load switching" and Figure 21: " Switching waveform")		85	-	ns
t _{r(Voff)}	Off voltage rise time	Vcc = 480 V, Ic = 12 A,	-	65	-	ns
t _{d(off)}	Turn-off delay time	$R_G = 10 \Omega$, $V_{GE} = 15 V$, $T_{C}=125 °C$ (see <i>Figure 19:</i> "		145	-	ns
t _f	Current fall time	Test circuit for inductive load switching" and Figure 21: " Switching waveform")	-	125	-	ns

Table 7: Switching energy (inductive load)

rabio i i dinicimi g di di gy (inductivo roda)							
Symbol Parameter		Test conditions		Тур.	Max.	Unit	
E _{on} ⁽¹⁾	Turn-on switching energy	Vcc = 480 V, Ic = 12 A,	-	165	-	μJ	
E _{off} ⁽²⁾	Turn-off switching energy	R _G = 10 Ω , V _{GE} = 15 V (see Figure 19: " Test circuit for inductive load switching")	-	255	-	μJ	
E _{ts}	Total switching energy	inductive load switching)		420	1	μJ	
E _{on} ⁽¹⁾	Turn-on switching energy	Vcc = 480 V, Ic = 12 A, R _G = 10 Ω , V _{GE} = 15 V,	1	250		μJ	
E _{off} ⁽²⁾	Turn-off switching energy	T _C =125 °C (see <i>Figure 19:</i> " <i>Test circuit for</i>	ı	445	ı	μJ	
Ets	Total switching energy	inductive load switching")		695	-	μJ	

Notes:

 $^{^{(1)}}$ Including the reverse recovery of the diode.

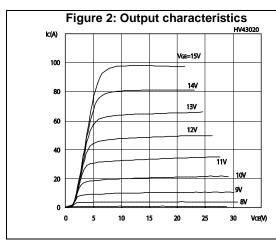
 $[\]ensuremath{^{(2)}}\mbox{Including}$ the tail of the collector current.

STGB19NC60KDT4, STGF19NC60KD, STGP19NC60KD

Table 8: Collector-emitter diode

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
\/_	Forward on voltage	I _F =12 A	-	1.9	-	V
V _F	Forward on-voltage	I _F =12 A, T _C =125 °C	-	1.6	-	V
t _{rr}	Reverse recovery time		-	31	-	ns
Qrr	Reverse recovery charge	I _F =12 A, V _R =40 V, di/dt=100 A/µs (see <i>Figure 22: " Diode reverse</i>	-	30	-	nC
I _{rrm}	Reverse recovery current	recovery waveform")	-	2	-	Α
t _{rr}	Reverse recovery time		-	50	-	ns
Qrr	Reverse recovery charge	I _F =12 A, V _R =40 V, T _C =125 °C, di/dt=100 A/µs (see <i>Figure 22: " Diode reverse</i>	-	70	-	nC
I _{rrm}	Reverse recovery current	recovery waveform")	-	4	-	Α

2.1 Electrical characteristics (curves)



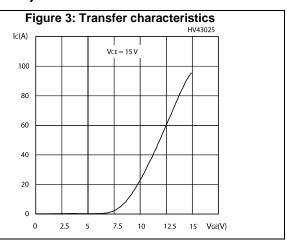
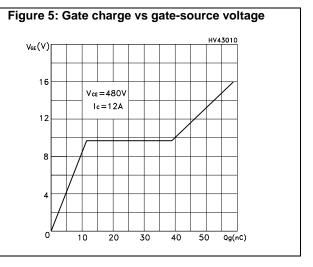
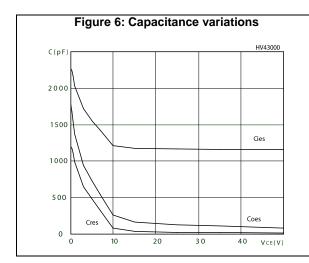


Figure 4: Collector-emitter on voltage vs temperature 25A 2.4 2.25 2.1 1.95 1.8 12A 1.65 1.5 6A 1.35 -75 -50 -25 0 25 50 75 100 125 150 TJ(°C)





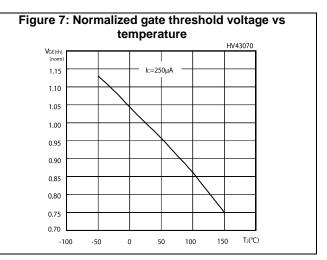
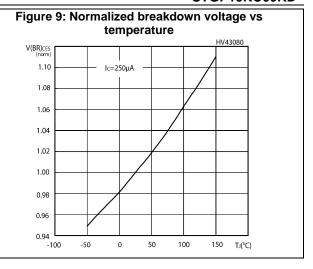
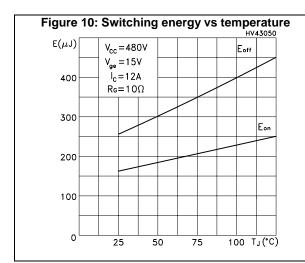
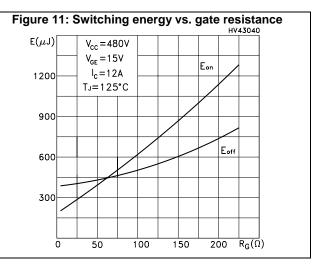
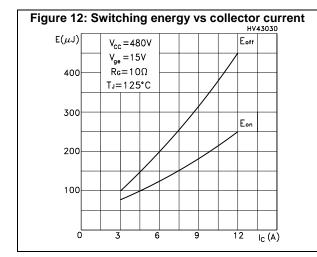


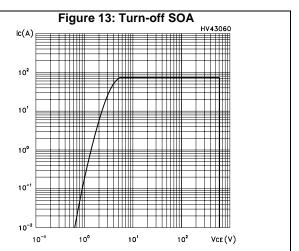
Figure 8: Collector-emitter on voltage vs collector current VCE(sat) 2.55 T_J= -50°C 2.3 2.05 1.8 T_J= 25°C 1.55 1.3 1.05 T_J=125°C 0.8 0 10 15 20 25 30 35











57

Figure 14: Emitter-collector diode characteristics

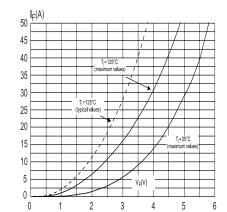


Figure 15: Thermal impedance for TO-220, D²PAK $\frac{280701H}{\delta = 0.5}$ 0.2

0.1

0.05 $\frac{10^{-1}}{10^{-5}}$ SINGLE PULSE $\frac{10^{-2}}{10^{-5}}$ $\frac{10^{-4}}{10^{-3}}$ $\frac{10^{-2}}{10^{-3}}$ $\frac{10^{-2}}{10^{-1}}$ $\frac{10^{-2}}{10^{-5}}$

Figure 16: Thermal impedance for TO-220FP

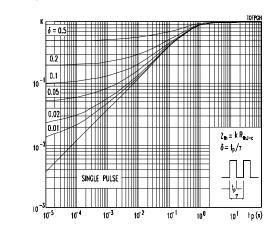
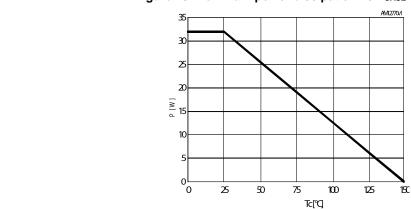


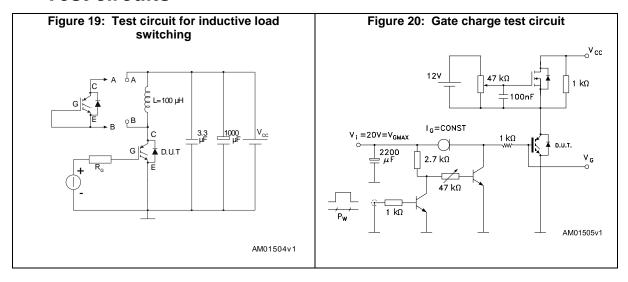
Figure 17: Maximum DC collector current vs T_{CASE} for TO-220FP

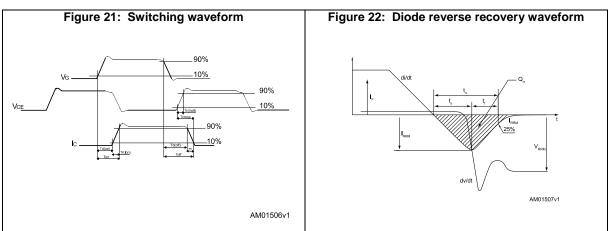
| No. | CASE | TO-220FP | TO-220F

Figure 18: Maximum power dissipation vs T_{CASE} for TO-220FP



3 Test circuits





4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

4.1 D²PAK (TO-263) type A package information

SEATING PLANE
COPLANARITY A1

R

GAUGE PLANE
V2

0079457_23_A

Figure 23: D²PAK (TO-263) type A package outline

Table 9: D²PAK (TO-263) type A package mechanical data

mm					
Dim.		mm			
	Min.	Тур.	Max.		
Α	4.40		4.60		
A1	0.03		0.23		
b	0.70		0.93		
b2	1.14		1.70		
С	0.45		0.60		
c2	1.23		1.36		
D	8.95		9.35		
D1	7.50	7.75	8.00		
D2	1.10	1.30	1.50		
E	10.00		10.40		
E1	8.50	8.70	8.90		
E2	6.85	7.05	7.25		
е		2.54			
e1	4.88		5.28		
Н	15.00		15.85		
J1	2.49		2.69		
L	2.29		2.79		
L1	1.27		1.40		
L2	1.30		1.75		
R		0.40			
V2	0°		8°		



9.75

16.9

2.54

5.08

Figure 24: D²PAK (TO-263) type A recommended footprint (dimensions are in mm)

4.2 D²PAK (TO-263) type B package information

Figure 25: D²PAK (TO-263) type B package outline

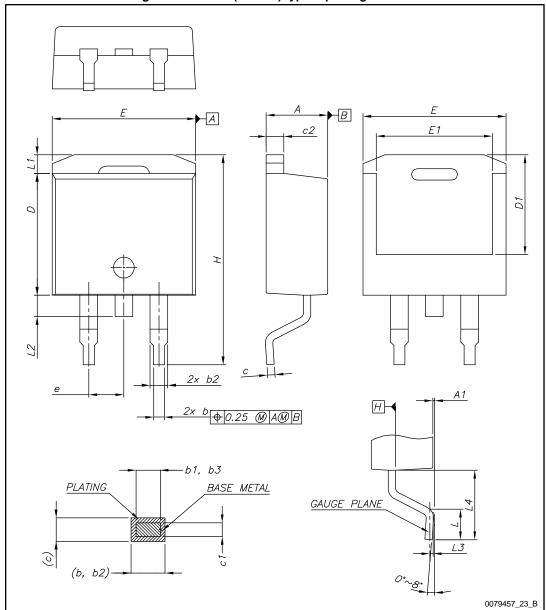


Table 10: D²PAK (TO-263) type B mechanical data

Table 10: D ² PAK (10-263) type B mechanical data							
Dim.		mm					
Dim.	Min.	Тур.	Max.				
А	4.36		4.56				
A1	0		0.25				
b	0.70		0.90				
b1	0.51		0.89				
b2	1.17		1.37				
b3	1.36		1.46				
С	0.38		0.694				
c1	0.38		0.534				
c2	1.19		1.34				
D	8.60		9.00				
D1	6.90		7.50				
Е	10.15		10.55				
E1	8.10		8.70				
е		2.54 BSC					
Н	15.00		15.60				
L	1.90		2.50				
L1			1.65				
L2			1.78				
L3		0.25					
L4	4.78		5.28				

9.75

16.9

1.6

2.54

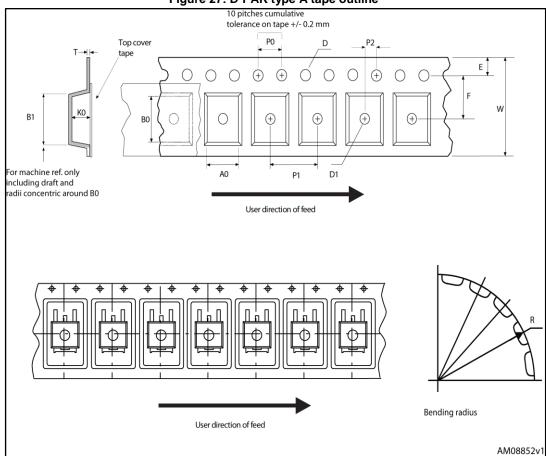
5.08

Figure 26: D²PAK (TO-263) type B recommended footprint (dimensions are in mm)



4.3 D²PAK type A packing information

Figure 27: D²PAK type A tape outline



A 40mm min. access hole at slot location

Tape slot in core for tape start 2.5mm min.width

AM06038v1

Figure 28: D2PAK type A reel outline

Table 11: D2PAK type A tape and reel mechanical data

Таре			Reel		
Dim.	m	ım	Dim.	mm	
Dim.	Min.	Max.	Dilli.	Min.	Max.
A0	10.5	10.7	Α		330
В0	15.7	15.9	В	1.5	
D	1.5	1.6	С	12.8	13.2
D1	1.59	1.61	D	20.2	
Е	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	Т		30.4
P0	3.9	4.1			
P1	11.9	12.1	Base q	uantity	1000
P2	1.9	2.1	Bulk quantity		1000
R	50				
Т	0.25	0.35			
W	23.7	24.3			

4.4 D²PAK type B packing information

Figure 29: D²PAK type B tape outline

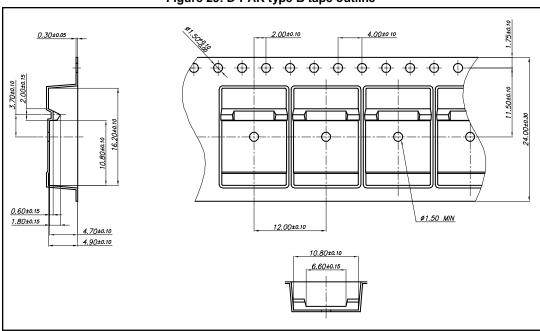


Figure 30: D²PAK type B reel outline

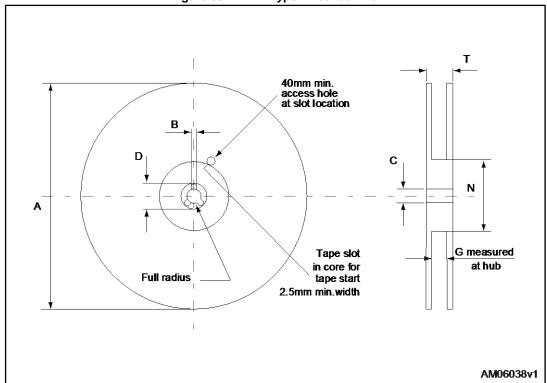


Table 12: D²PAK type B reel mechanical data

Dim	mm			
Dim.	Min.	Max.		
A		330		
В	1.5			
С	12.8	13.2		
D	20.2			
G	24.4	26.4		
N	100			
Т		30.4		

4.5 TO-220FP package information

Figure 31: TO-220FP package outline

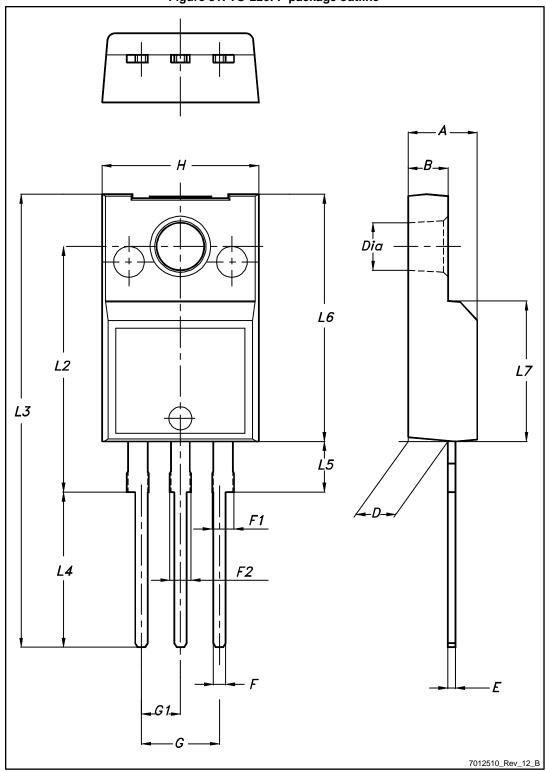


Table 13: TO-220FP package mechanical data

Table 101 10 == 01 Partial Grant and a state of the sta				
Dim.	mm			
	Min.	Тур.	Max.	
Α	4.4		4.6	
В	2.5		2.7	
D	2.5		2.75	
E	0.45		0.7	
F	0.75		1	
F1	1.15		1.70	
F2	1.15		1.70	
G	4.95		5.2	
G1	2.4		2.7	
Н	10		10.4	
L2		16		
L3	28.6		30.6	
L4	9.8		10.6	
L5	2.9		3.6	
L6	15.9		16.4	
L7	9		9.3	
Dia	3		3.2	

4.6 TO-220 type A package information

Figure 32: TO-220 type A package outline

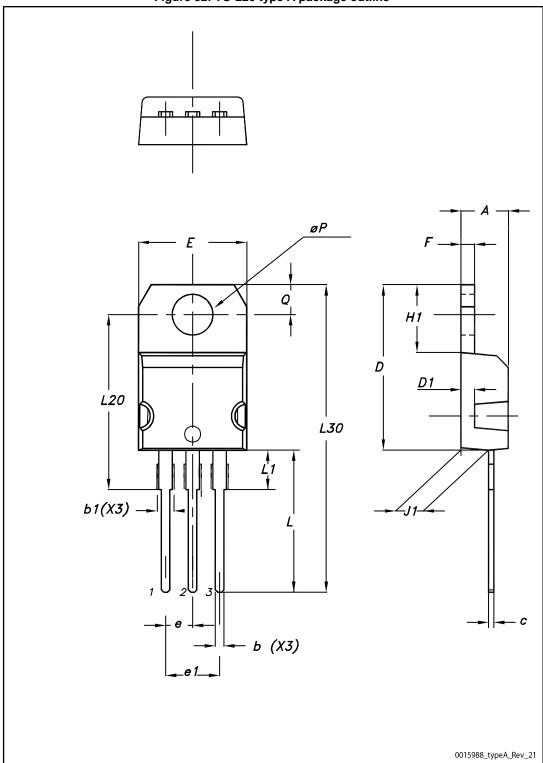


Table 14: TO-220 type A package mechanical data

Dim.	mm		
	Min.	Тур.	Max.
А	4.40		4.60
b	0.61		0.88
b1	1.14		1.55
С	0.48		0.70
D	15.25		15.75
D1		1.27	
Е	10.00		10.40
е	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13.00		14.00
L1	3.50		3.93
L20		16.40	
L30		28.90	
øΡ	3.75		3.85
Q	2.65		2.95

5 Revision history

Table 15: Document revision history

	Ţ	
Revision	Changes	
1	Initial release	
2	 Value on Table 3: Thermal resistance has been changed. Inserted Figure 16: Thermal impedance for TO-220, D²PAK and Figure 17: Thermal impedance for TO-220FP 	
3	Added: Figure 18 and Figure 19 on page 8.	
4	Modified internal schematic diagram on cover page Modified Table 2: "Absolute maximum ratings", Table 3: "Thermal data", and Table 4: "Static characteristics". Modified Figure 3: "Transfer characteristics", Figure 4: "Collector- emitter on voltage vs temperature" and Figure 8: "Collector-emitter on voltage vs collector current". Updated Section 4: "Package information". Minor text changes.	
	1 2 3	

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